NSN 5961-01-023-9464

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-023-9464 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 1.320 inches **Overall Diameter:** Between 0.350 inches and 0.420 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 breakover voltage, dc **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5221 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0